

MP04---590

DS5371-3.1 October 2001

Dual Thyristor, Thyristor/Diode Module

Replaces April 2001 version, DS5371-2.2

FEATURES

- Dual Device Module
- Electrically Isolated Package
- Pressure Contact Construction
- International Standard Footprint
- Alumina (Non Toxic) Isolation Medium
- Integral Water Cooled Heatsink

APPLICATIONS

- Motor Control
- Controlled Rectifier Bridges
- Heater Control
- AC Phase Control

VOLTAGE RATINGS

Type Number	Repetitive Peak Voltages V _{DRM} V _{RRM} V	Conditions
MP04590-18 MP04590-16 MP04590-14	1800 1600 1400	$\begin{split} T_{vj} &= 0^{\circ} \text{ to } 125^{\circ}\text{C}, \\ I_{DRM} &= I_{RRM} = 50\text{mA} \\ V_{DSM} &= V_{RSM} = \\ V_{DRM} &= V_{RRM} + 100\text{V} \\ \text{respectively} \end{split}$

Lower voltage grades available.

ORDERING INFORMATION

Order As:

MP04HBT590-18 or MP04HBT-16 or MP04HBT14 MP04HBP590-18 or MP04HBP-16 or MP04HBP14 MP04HBN590-18 or MP04HBN-16 or MP04HBN14

Note: When ordering, please use the whole part number.

 KEY PARAMETERS

 V_{DRM}
 1800

 I_{T(AV)}
 5957

 I_{TSM(per arm)}
 1680

V_{isol}

1800V 595A 16800A 3000V

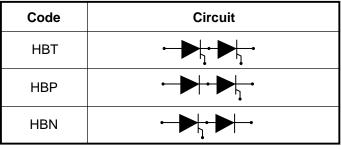
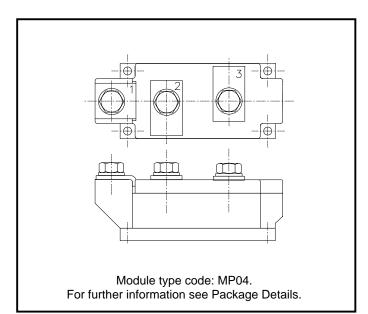


Fig.1 Circuit diagrams







ABSOLUTE MAXIMUM RATINGS - PER ARM

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

Symbol	Parameter	Test Conditions		Max.	Units
I _{T(AV)}	Mean on-state current	Half wave resistive load	T _{case} = 75°C	595	А
			T _{case} = 85°C	505	А
I _{T(RMS}	RMS value	$T_{case} = 75^{\circ}C$		935	А
I _{TSM}	Surge (non-repetitive) on-current	8.3ms half sine, T _j = 125°C		16.8	kA
l²t	l ² t for fusing	V _R = 0		1411 X 10 ³	A²s
I _{TSM}	Surge (non-repetitive) on-current	8.3ms half sine, T _j = 125°C		13.5	kA
l²t	I ² t for fusing	$V_{R} = 50\% V_{DRM}$		911 X 10 ³	A²s
I _{TSM}	Surge (non-repetitive) on-current	10ms half sine, T _j = 125°C		15.7	kA
l²t	l ² t for fusing	V _R = 0		1232 X 10 ³	A ² s
I _{TSM}	Surge (non-repetitive) on-current	10ms half sine, $T_j = 125^{\circ}C$		12.6	kA
l²t	I ² t for fusing	$V_{R} = 50\% V_{DRM}$		794 X 10 ³	A ² s
V _{isol}	Isolation voltage	Commoned terminals to base plate. AC RMS, 1 min, 50Hz		3000	V



THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance - junction to case	dc	-	0.056	°C/kW
	(per thyristor or diode)	Half wave	-	0.060	°C/kW
		3 Phase	-	0.066	°C/kW
R _{th(c-hs)}	Thermal resistance - case to heatsink	Mounting torque = 5Nm	-	0.02	°C/kW
	(per thyristor or diode)	with mounting compound			
T _{vj}	Virtual junction temperature	Reverse (blocking)	-	125	°C
T _{stg}	Storage temperature range	-	-40	130	°C
-	Screw torque	Mounting - M6	-	6 (35)	Nm (lb.ins)
		Electrical connections - M10	-	12 (106)	Nm (lb.ins)
-	Weight (nominal)	-	-	1580	g

DYNAMIC CHARACTERISTICS - THYRISTOR

Symbol	Parameter	Test Conditions	Min.	Max.	Units
I _{RRM} /I _{DRM}	Peak reverse and off-state current	At V_{RRM}/V_{DRM} , $T_j = 125^{\circ}C$	-	50	mA
dV/dt	Linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C	-	1000	V/µs
dl/dt	Rate of rise of on-state current	From 67% V _{DRM} to 1500A, gate source 1.5A,	-	500	A/μs
		t _r = 0.5μs, T _j = 125°C			
V _{T(TO)}	Threshold voltage	At T _{vj} = 125°C. See note 1	-	0.85	V
r _T	On-state slope resistance	At T _{vj} = 125°C. See note 1	-	0.38	mΩ

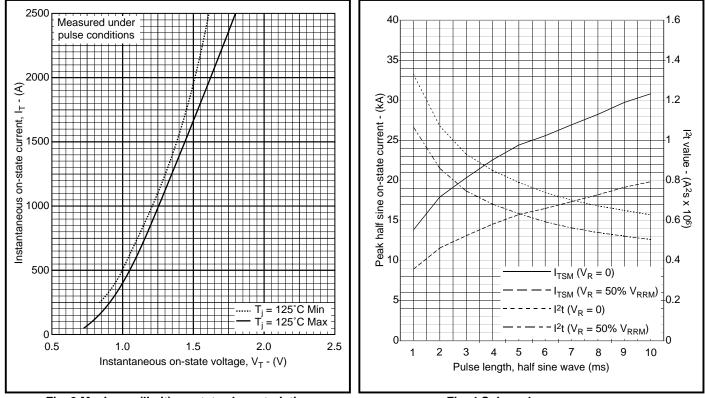
Note 1: The data given in this datasheet with regard to forward voltage drop is for calculation of the power dissipation in the semiconductor elements only. Forward voltage drops measured at the power terminals of the module will be in excess of these figures due to the impedance of the busbar from the terminal to the semiconductor.



GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V _{GT}	Gate trigger voltage	$V_{\text{DRM}} = 5V, T_{\text{case}} = 25^{\circ}\text{C}$	3.5	V
I _{GT}	Gate trigger current	$V_{\text{DRM}} = 5V, T_{\text{case}} = 25^{\circ}\text{C}$	200	mA
V _{GD}	Gate non-trigger voltage	At V_{DRM} , $T_{\text{case}} = 125^{\circ}\text{C}$	0.25	V
V _{FGM}	Peak forward gate voltage	Anode positive with respect to cathode	30	V
V _{FGN}	Peak forward gate voltage	Anode negative with respect to cathode	0.25	V
V _{RGM}	Peak reverse gate voltage	-	5	V
I _{FGM}	Peak forward gate current	Anode positive with respect to cathode	10	А
P _{GM}	Peak gate power	See table fig. 5	150	W
P _{G(AV)}	Mean gate power	-	10	w

CURVES



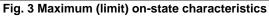
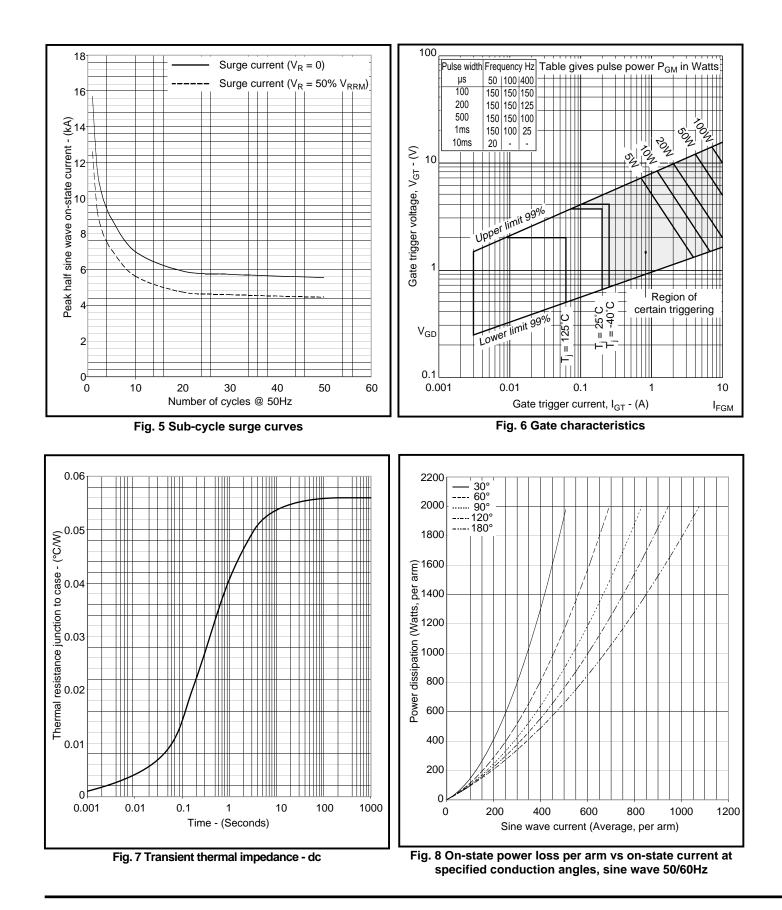
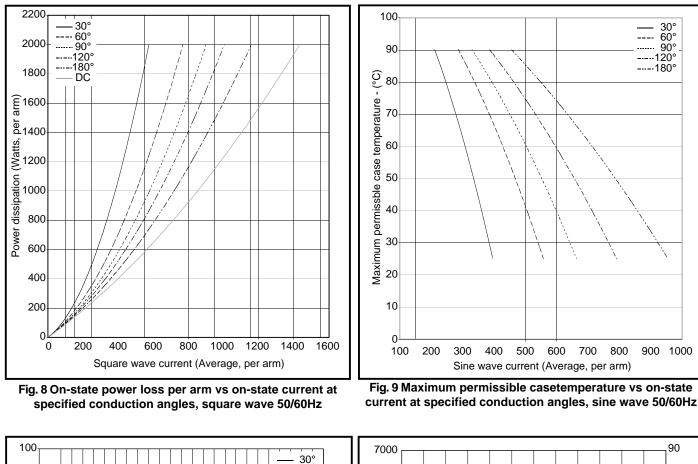


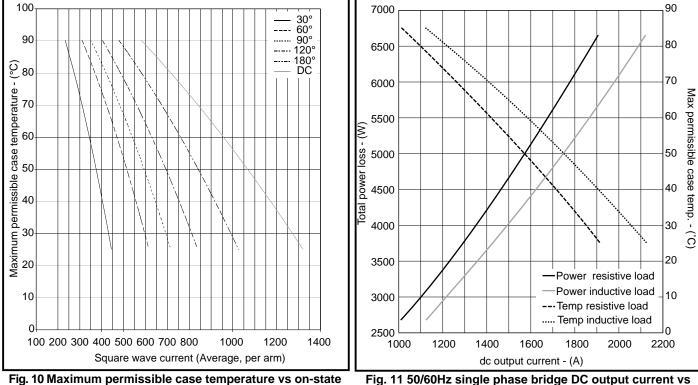
Fig. 4 Sub-cycle surge curves

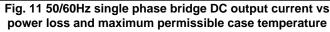












current at specified conduction angles, square wave 50/60Hz



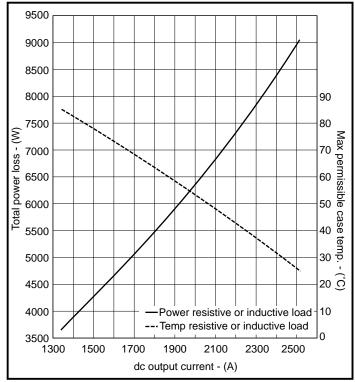
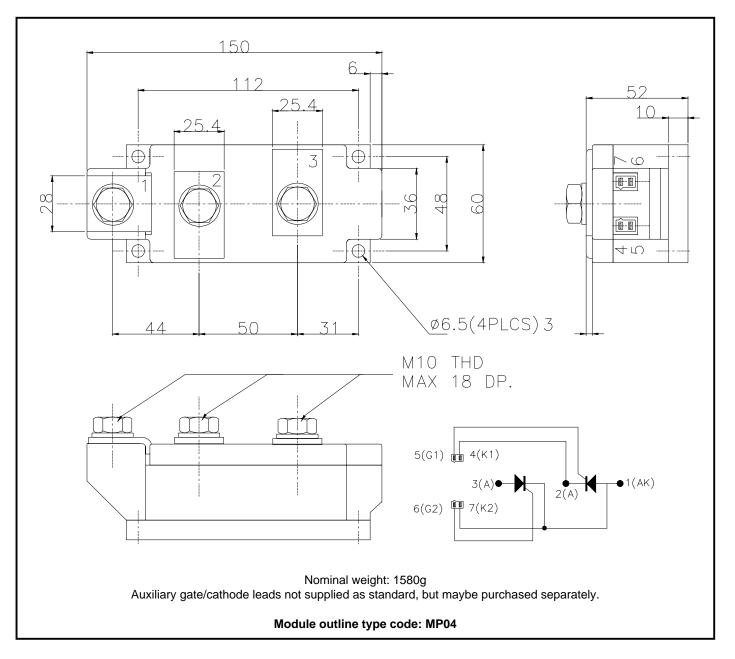


Fig. 12 50/60Hz Three phase bridge DC output current vs power loss and maximum permissible case temperature



PACKAGE DETAILS

For further package information, please visit our website or contact your nearest Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





MOUNTING RECOMMENDATIONS

Adequate heatsinking is required to maintain the base temperature at 75 C if full rated current is to be achieved. Power dissipation may be calculated by use of V_{T(TO)} and r_T information in accordance with standard formulae. We can provide assistance with calculations or choice of heatsink if required.

The heatsink surface must be smooth and flat; a surface finish of N6 (32μ in) and a flatness within 0.05mm (0.002") are recommended.

Immediately prior to mounting, the heatsink surface should be lightly scrubbed with fine emery, Scotch Brite or a mild chemical etchant and then cleaned with a solvent to remove oxide build up and foreign material. Care should be taken to ensure no foreign particles remain.

An even coating of thermal compound (eg. Unial) should be applied to both the heatsink and module mounting surfaces. This should ideally be 0.05mm (0.002") per surface to ensure optimum thermal performance.

After application of thermal compound, place the module squarely over the mounting holes, (or 'T' slots) in the heatsink. Fit and finger tighten the recommended fixing bolts at each end. Using a torque wrench, continue to tighten the fixing bolts by rotating each bolt in turn no more than 1/4 of a revolution at a time, until the required torque of 6Nm (55lbs.ins) is reached on all bolts at both ends.

It is not acceptable to fully tighten one fixing bolt before starting to tighten the others. Such action may DAMAGE the module.

POWER ASSEMBLY CAPABILITY

The Power Assembly group provides support for those customers requiring more than the basic semiconductor switch. Using CAD design tools the group has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of Dynex semiconductors.

An extensive range of air and liquid cooled assemblies is available covering the range of circuit designs in general use today.

HEATSINKS

The Power Assembly group has a proprietary range of extruded aluminium heatsinks. These were designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or customer service office.





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Target Information: This is the most tentative form of information and represents a very preliminary specification. No actual design work on the product has been started.

Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

Advance Information: The product design is complete and final characterisation for volume production is well in hand.

No Annotation: The product parameters are fixed and the product is available to datasheet specification.

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